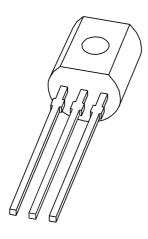
## **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# **2N3906** PNP switching transistor

Product specification Supersedes data of 1999 Apr 23 2004 Oct 11





## **PNP** switching transistor

2N3906

#### **FEATURES**

- Low current (max. 200 mA)
- Low voltage (max. 40 V).

#### **APPLICATIONS**

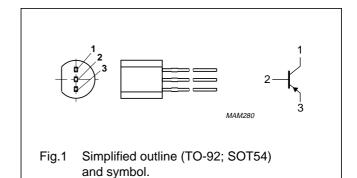
• High-speed switching in industrial applications.

#### **DESCRIPTION**

PNP switching transistor in a TO-92; SOT54 plastic package. NPN complement: 2N3904.

#### **PINNING**

PIN	DESCRIPTION
1	collector
2	base
3	emitter



#### **ORDERING INFORMATION**

TYPE NUMBER	PACKAGE				
I TPE NOWIBER	NAME	DESCRIPTION	VERSION		
2N3906	SC-43A	BA plastic single-ended leaded (through hole) package; 3 leads			

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	-40	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	-6	V
I <sub>C</sub>	collector current (DC)		_	-200	mA
I <sub>CM</sub>	peak collector current		_	-300	mA
I <sub>BM</sub>	peak base current		_	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	_	500	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	250	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

## PNP switching transistor

2N3906

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

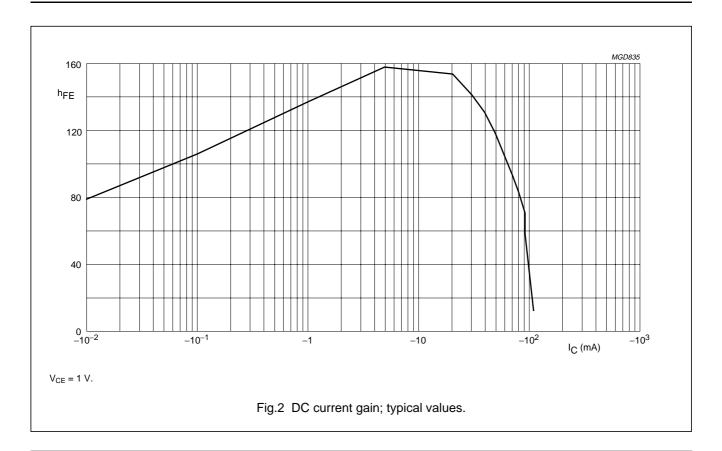
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$	Ī-	-50	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -6 \text{ V}; I_C = 0 \text{ A}$	_	-50	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -1 V; note 1; see Fig.2			
		$I_{C} = -0.1 \text{ mA}$	60	_	
		$I_C = -1 \text{ mA}$	80	_	
		$I_C = -10 \text{ mA}$	100	300	
		$I_C = -50 \text{ mA}$	60	_	
		$I_{C} = -100 \text{ mA}$	30	_	
V <sub>CEsat</sub>	collector-emitter saturation	$I_C = -10 \text{ mA}; I_B = -1 \text{ mA}; \text{ note } 1$	_	-200	mV
	voltage	$I_C = -50 \text{ mA}$ ; $I_B = -5 \text{ mA}$ ; note 1	_	-200	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -1 \text{ mA}; \text{ note } 1$	Ī-	-850	mV
		$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}; \text{ note 1}$	_	-950	mV
C <sub>c</sub>	collector capacitance	$V_{CB} = -5 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	_	4.5	pF
Ce	emitter capacitance	$I_C = i_C = 0$ ; $V_{EB} = -500 \text{ mV}$ ; $f = 1 \text{ MHz}$	_	10	pF
f <sub>T</sub>	transition frequency	$V_{CE} = -20 \text{ V}; I_{C} = -10 \text{ mA}; f = 100 \text{ MHz}$	250	_	MHz
F	noise figure	$V_{CE}$ = -5 V; $I_{C}$ = -100 μA; $R_{S}$ = 1 kΩ; $f$ = 10 Hz to 15.7 kHz	_	4	dB
Switching t	imes (between 10 % and 90 % lev	els); see Fig.3			
t <sub>on</sub>	turn-on time	$I_{Con} = -10 \text{ mA}; I_{Bon} = -1 \text{ mA};$	_	65	ns
t <sub>d</sub>	delay time	I <sub>Boff</sub> = 1 mA	_	35	ns
t <sub>r</sub>	rise time	1	_	35	ns
t <sub>off</sub>	turn-off time	]	_	300	ns
ts	storage time		_	225	ns
t <sub>f</sub>	fall time		_	75	ns

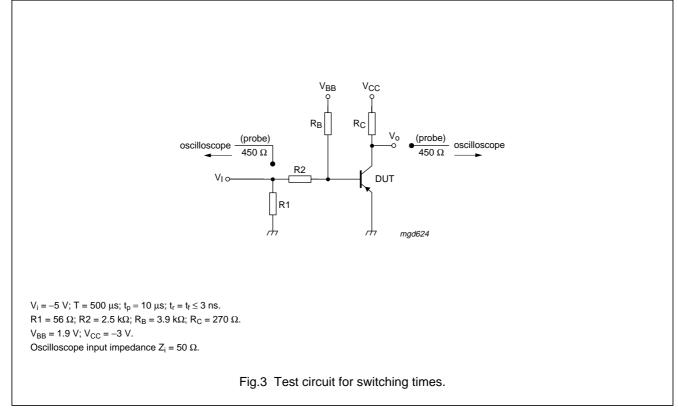
#### Note

1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

## PNP switching transistor

2N3906





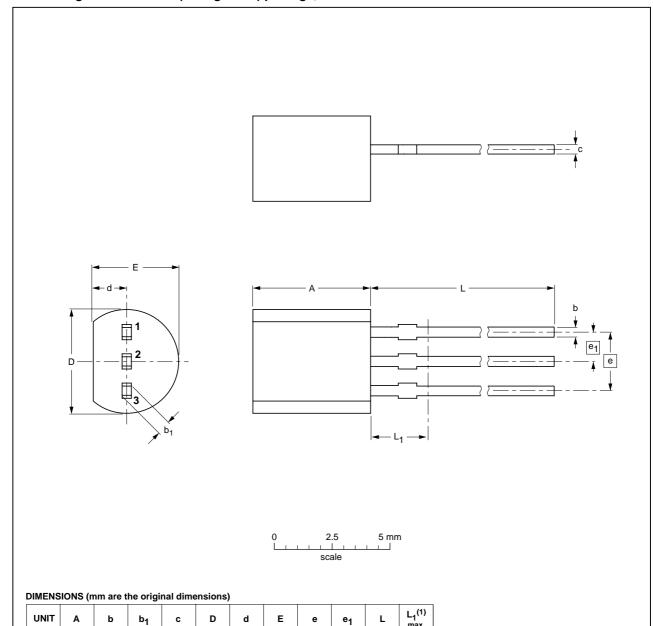
## PNP switching transistor

2N3906

#### **PACKAGE OUTLINE**

#### Plastic single-ended leaded (through hole) package; 3 leads

SOT54



### mm

0.48

0.40

5.0

0.66

0.55

0.45

0.38

4.8

4.4

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

1.4

3.6

OUTLINE REFERENCES			EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT54		TO-92	SC-43A			<del>97-02-28</del> 04-06-28

1.27

2.54

14.5

12.7

2.5

#### PNP switching transistor

2N3906

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LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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